

# GH17805D2AS

Insert Frame Structure, Resin Type Laser Diode  
for CD Audio/CD-ROM Drive(780nm-5mW)

## ■ Features

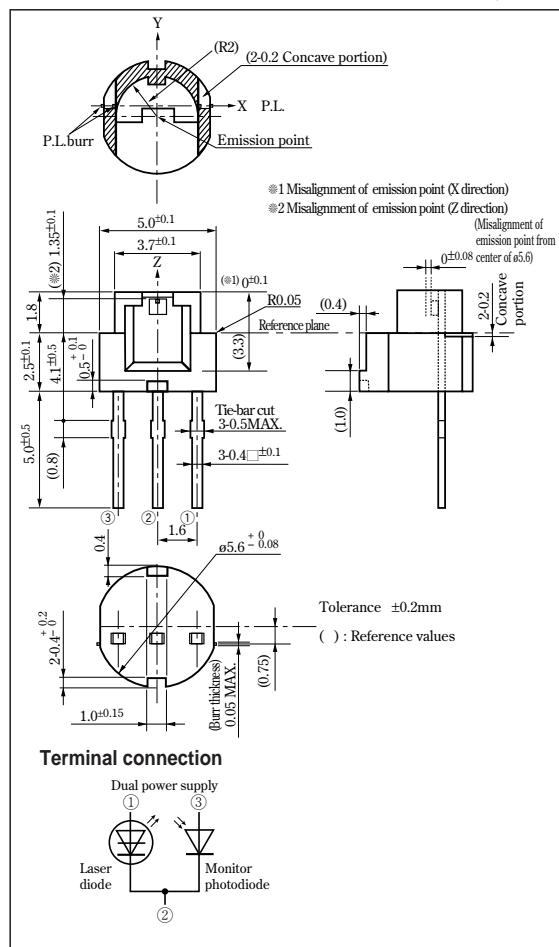
- (1)  $\phi 5.6\text{mm}$  open type insert lead frame structure  
(Optically compatible with the conventional  $\phi 5.6\text{mm}$  package)
- (2) Maximum optical power output : 5mW (CW)
- (3) Wavelength : TYP. 780nm
- (4) Low current drive type

## ■ Applications

- (1) CD audio players
- (2) CD-ROM drives

## ■ Outline Dimensions

(Unit : mm)



## ■ Absolute Maximum Ratings

(T<sub>c</sub>=25°C ※1)

Parameter	Symbol	Rating	Unit
※3 Optical power output	P <sub>o</sub>	5	mW
Reverse voltage	Laser	V <sub>rl</sub>	2
	Monitor photodiode	V <sub>rd</sub>	30
※1 Operating temperature	T <sub>op(c)</sub>	-10 to +70	°C
Storage temperature	T <sub>stg</sub>	-40 to +85	°C
※2 Soldering temperature	T <sub>sl</sub>	260	°C

※1 Case temperature

※2 At the position of 0.6mm or more from the lead base (5s)

※3 CW (Continuous Wave) drive

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### ■ Electro-optical Characteristics<sup>\*1</sup>

(T<sub>c</sub>=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Threshold current	I <sub>th</sub>	-	-	(12)	20	mA	
Operating current	I <sub>op</sub>	P <sub>o</sub> =3mW	-	(18)	25	mA	
Operating voltage	V <sub>op</sub>		-	(2.0)	2.3	V	
Wavelength	λ <sub>p</sub>		770	(780)	795	nm	
Half intensity angle	<sup>*2*</sup> Parallel		θ//	6	(11)	18	°
	<sup>*2*</sup> Perpendicular		θ⊥	27	(40)	49	°
<sup>*4</sup> Ripple	R <sub>i</sub>		-20	-	+20	%	
Misalignment angle	<sup>*3</sup> Parallel		Δθ//	-2	-	+2	°
	<sup>*3</sup> Perpendicular		Δθ⊥	-3	-	+3	°
Differential efficiency	η <sub>d</sub>		$\frac{2mW}{I(3mW)-I(1mW)}$	0.35	(0.65)	0.95	mW/mA
Interference pattern intensity	α		P <sub>o</sub> =3mW	-	-	0.97	-
Kink	K-LI	-	-	-	10	%	

<sup>\*1</sup> Initial value, CW (Continuous Wave) drive

<sup>\*2</sup> Angle at 50% peak intensity (full-width at half-maximum)

<sup>\*3</sup> Parallel to the junction plane (X-Z plane), Perpendicular to the junction plane (Y-Z plane)

<sup>\*4</sup> R<sub>i</sub>=ΔP/P ΔP : the maximum deviation of the far field pattern from its approximate curve P : the peak of the approximate curve

### ■ Electrical Characteristics of Photodiode

(T<sub>c</sub>=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current	I <sub>m</sub>	P <sub>o</sub> =3mW, V <sub>rd</sub> =5V	0.02	(0.05)	0.1	mA
Dark current	I <sub>D</sub>	V <sub>rd</sub> =5V	-	-	150	nA

#### ● Operating and handling precautions

- (1) This product employs open type package. Be careful not to touch gold wires, laser chips, or monitor sub-mount chips directly, or characteristics may be damaged.
- (2) The lead pins of this product consist of silver-plating.  
Do not operate under the conditions of freezing or dew formation. The use in such conditions may cause short circuits due to silver migration.
- (3) Please finish soldering within 7 days, or keep the products in the N<sub>2</sub>-purged box after opening the package to prevent silver oxidation or damage to solderability.

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